NSN 5961-01-386-2614

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-386-2614 **Inclosure Material:** Plastic **Overall Length:** 3.06 millimeters **Overall Height:** 1.2 millimeters **Overall Width:** 2.5 millimeters **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 repetitive peak reverse voltage **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 2.2 **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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